

Persistent current in a non-Hermitian Hatano-Nelson ring: Disorder-induced amplification

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Non-reciprocal hopping induces a synthetic magnetic flux which leads to the non-Hermitian Aharonov-Bohm effect. Since non-Hermitian Hamiltonians possess both real and imaginary eigenvalues, this effect allows the observation of real and imaginary persistent currents in a ring threaded by the synthetic flux²⁷. Motivated by this, we investigate the behavior of persistent currents in a disordered Hatano-Nelson ring with anti-Hermitian intradimer hopping. The disorder is diagonal and we explore three distinct models, namely the Aubry-André-Harper model, the Fibonacci model, both representing correlated disorder, and an uncorrelated (random) model. We conduct a detailed analysis of the energy spectrum and examine the real and imaginary parts of the persistent current under various conditions such as different ring sizes and filling factors. Interestingly, we find that real and imaginary persistent currents exhibit amplification in the presence of correlated disorder. This amplification is also observed in certain individual random configurations but vanishes after configuration averaging. Additionally, we observe both diamagnetic and paramagnetic responses in the current behavior and investigate aspects of persistent currents in the absence of disorder that have not been previously explored. Interestingly, we find that the intradimer bonds host only imaginary currents, while the interdimer bonds carry only real currents.

I. INTRODUCTION

Persistent current arises in a metal ring when electron mean free path exceeds ring circumference, enclosing magnetic flux. It was first predicted by Kulik¹ and later by Büttiker, Imry, and Landauer in the context of a 1D disordered ring². A few years later, the existence of persistent current was further affirmed by notable experimental investigations conducted on 10^7 isolated mesoscopic copper rings³ and an isolated gold ring⁴. So far, numerous studies have been conducted to explore persistent currents in various types of mesoscopic rings under different scenarios, both theoretically^{5–13} and experimentally^{14–17}.

In the aforementioned studies, it is noteworthy that all theoretical investigations are grounded in Hermitian models. Another crucial aspect of persistent currents is their reliance on a real electromagnetic potential within closed-loop structures. However, two seminal works by Hatano and Nelson showed that asymmetric coupling can induce a synthetic gauge field, which also makes the system non-Hermitian^{18,19}. Consequently, in recent years, several attempts have been made to study the effect of synthetic gauge fields utilizing non-reciprocal hopping^{20–27}. For instance, studies have examined 1D tight-binding lattices to explore transport properties²⁰, transport properties of light in 1D photonic lattices²¹, Bloch oscillations in the non-Hermitian Hatano-Nelson (HN) model²², 1D chains of noninteracting bosonic cavities²⁴, etc. In Ref.²⁷, it has been demonstrated that a magnetic flux can be achieved in a non-Hermitian Hatano-Nelson ring by incorporating anti-Hermitian intradimer hopping. In presence of this flux, both real and imaginary persis-

tent currents can be generated.

Inspired by recent work²⁷, we explore the behavior of persistent current in an HN ring with anti-Hermitian intradimer hopping under different disordered scenario. Specifically, three different types of disorder is considered, namely, the well-known Aubry-André-Harper (AAH) model^{28,29}, Fibonacci^{30,31}, and uncorrelated (random) disorder³². Additionally, we investigate several aspects in the absence of disorder that have not been previously discussed, specifically the characteristic features of the energy spectrum and persistent currents with varying ring sizes, and the influence of the filling factor. We also investigate the nature of the persistent current across different bonds of the ring.

The key results of the present work are: (i) while the real (imaginary) persistent currents display a notable increase in magnitude within the trivial (topological) regime, the smaller component of currents does not vanish entirely, (ii) correlated disorder induces anomalous signatures in the energy spectra, (iii) the presence of correlated disorder enhances the magnitude of real and imaginary persistent currents compared to the disorder-free scenario, (iv) tuning the synthetic magnetic flux allows for the realization of both diamagnetic and paramagnetic responses multiple times within a single flux period, surpassing the behavior observed in the disorder-free case, and (v) the persistent current is always imaginary in the intra-dimer bonds, with the real current being identically zero, while it is always real in the inter-dimer bonds, with the imaginary current being identically zero.

The rest of the paper is organized as follows. In the next section (Section II), we present the schematic diagram, model Hamiltonian, and the necessary theory to

compute the persistent current. In Section III, we discuss the results, including the energy spectrum, ground state energy, and real and imaginary persistent currents under different scenarios both in the absence and presence of disorder. We also include a detailed derivation for the bond-resolved persistent currents along with their features. Finally, we summarize our findings in Section IV.

II. THEORY

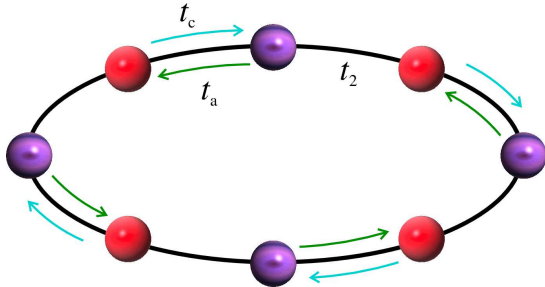


FIG. 1. (Color online.) A schematic representation of a Hatano-Nelson ring consisting of eight sites is shown with two sublattices labeled, sublattice A in red and sublattice B in violet. The intradimer hopping strength in the clockwise direction is t_c , shown in cyan, and in the counterclockwise direction is t_a . The interdimer hopping strength is denoted by t_2 .

The schematic representation of an HN ring is shown in Fig. 1. The lattice structure is composed of two sites per unit cell. The asymmetry is introduced in the intradimer bond. The corresponding nearest-neighbor tight-binding Hamiltonian is described as

$$\begin{aligned}
 H = & \sum_{n=1}^N \left(\epsilon_{n,A} c_{n,A}^\dagger c_{n,A} + \epsilon_{n,B} c_{n,B}^\dagger c_{n,B} \right) \\
 & + \sum_{n=1}^N \left(t_c c_{n,A}^\dagger c_{n,B} + t_a c_{n,B}^\dagger c_{n,A} \right) \\
 & + \sum_{n=1}^{N-1} \left(t_2 c_{n,B}^\dagger c_{n+1,A} + h.c. \right) \\
 & + \left(t_2 c_{N,B}^\dagger c_{1,A} + h.c. \right), \quad (1)
 \end{aligned}$$

where N is the number of unit cells in the HN ring. A and B are the two sublattices. $c_{n,\alpha}^\dagger$ ($c_{n,\alpha}$) is the creation (annihilation) operator in the n -th unit cell in the sublattice α ($= A, B$). The first and second terms in Eq. 1 represent the on-site terms, where $\epsilon_{n,A}$ and $\epsilon_{n,B}$ are the on-site energies at the n -th unit cell in the A and B sublattices, respectively. The third term is the non-reciprocal intracell hopping term. t_c is the hopping strength from sublattice- A to sublattice- B (clockwise sense) and t_a is the hopping strength from sublattice- B to sublattice- A (anticlockwise sense) in the same unit cell. The non-hermiticity is introduced in the system through the intracell hopping and

$t_c = -t_a^*$, that is the intracell hopping is antihermitian. The fourth term is the intercell hopping term, where t_2 is the intercell hopping strength. The fifth term connects the first and N -th unit cells through the intercell hopping strength t_2 .

The disorder in the ring is introduced through the on-site energies. In this work, we consider three different types of disorder: (i) the Aubry-André-Harper (AAH) model^{28,29}, (ii) the Fibonacci model^{30,31}, and (iii) a random distribution³². The first two models are well-known correlated disorder, while the third model introduces uncorrelated disorder, as the name suggests.

The AAH model has the functional form for the A sublattice as $\epsilon_{n,A} = W \cos[2\pi b(2n-1)]$ and for B -sublattice $\epsilon_{n,B} = W \cos[2\pi b(2n)]$. Here W is the strength of disorder. b is an irrational number and considered as²⁸ $b = (1 + \sqrt{5})/2$.

The Fibonacci sequence can be obtained iteratively with the modified relation $S_n = S_{n-1}S_{n-2}$ and the initial conditions $S_0 = Y$ and $S_1 = X$. Using these definitions, the first few sequences are $Y, X, XY, XYX, XYXXY, XYXXYXYX$. X and Y are treated as two basic units of the ring. To specify the on-site potentials based on this sequence, we assign values to the potentials according to whether the site unit is X or Y . Specifically, when the site unit is X , $\epsilon_{n,A/B} = W$ and when it is Y , $\epsilon_{n,A/B} = -W$.

For the uncorrelated disorder, all the on-site potentials will be picked up randomly from a box distribution between $-W$ to W .

The intracell hopping can be considered as $t_c = t + i\gamma$ and $t_a = -t - i\gamma$, where both t and γ are real numbers. They can be written in polar form as $t_c = |t_1|e^{i\phi}$ and $t_a = -|t_1|e^{-i\phi}$, where the hopping amplitude $|t_1| = \sqrt{t^2 + \gamma^2}$ and $e^{i\phi}$ is the Peierls phase factor. Over a complete cycle the total phase acquired is $e^{iN\phi}$ and $\Phi = N\phi$, where Φ can be identified as a real magnetic field generated by the non-Hermitian system²⁷. In our system, the interdimer hopping strength t_2 is always real.

At absolute zero temperature, electrons in a system will occupy the energy levels starting from the lowest available level, filling them sequentially in accordance with the Pauli exclusion principle for the spin-less case. If the number of electrons in the system is N_e , and this corresponds to the index m of the highest occupied energy level, then the ground state energy E_G of the system can be determined by summing the energies of all occupied levels up to m as

$$E_G = \sum_{n=1}^m E_n. \quad (2)$$

As the Hamiltonian of the system is non-Hermitian, its eigenvalues will be complex and therefore the persistent current will have both the real and imaginary parts. The real and imaginary persistent currents for the n -th eigen-

state can be defined as²⁷

$$\text{Re}[I_n] = -c \frac{\partial}{\partial \Phi} \text{Re}[E_n] \quad (3)$$

$$\text{Im}[I_n] = -c \frac{\partial}{\partial \Phi} \text{Im}[E_n] \quad (4)$$

where c is the speed of light in free space. The net real and imaginary persistent currents by the occupied electronic states will be then

$$\text{Re}[I] = \sum_{n=1}^m \text{Re}[I_n] \quad (5)$$

$$\text{Im}[I] = \sum_{n=1}^m \text{Im}[I_n]. \quad (6)$$

III. RESULTS AND DISCUSSION

Throughout the discussion, all energies are measured in units of eV. The intercell hopping is fixed at $t_2 = 1$ eV. We first consider the case without disorder and discuss several important aspects that have not been explored earlier.

A. Absence of disorder

First, we study the behavior of the complex energy spectrum as a function of Φ as shown in Fig. 2. We consider the number of unit cells $N = 8$. Three different cases are considered here, namely, the topological phase $t_1 < t_2$, trivial phase $t_1 > t_2$, and the transition point from topological to trivial phase $t_1 = t_2$.

In the topological phase ($t_1 < t_2$), the real energy spectrum exhibits a gap which was identified as a real line gap in an earlier study²⁷ as shown in Fig. 2(a). A real (imaginary) line gap exists if the \mathbf{k} -space non-Hermitian Hamiltonian is invertible for all \mathbf{k} values and all the real (imaginary) eigenvalues are finite³³. The imaginary eigenvalues continuously evolve with Φ and the spectrum is gapless as depicted in Fig. 2(b). Both the real and imaginary energy spectra oscillate with Φ with a period 2π .

At the transition point ($t_1 = t_2$), the non-Hermitian Hamiltonian yields the same set of real and imaginary eigenvalues. This is evident from the expression of the n -th eigen energy $E_n = \pm \sqrt{t_2^2 - |t_1|^2 + 2|t_1|t_2 i \sin\left[\frac{2\pi}{N}(n + \Phi/\Phi_0)\right]}$, where Φ_0 is the magnetic flux quantum. Consequently, the real and imaginary eigenvalues are identical as a function of Φ as shown in Figs. 2(c) and (d), respectively. Both the spectra exhibit gapless band structure.

The trivial phase ($t_1 > t_2$) presents a completely opposite scenario compared to the topological phase. The real energy values continuously evolve with Φ and the corresponding spectrum is gapless as depicted in Fig. 2(e). On the other hand, the imaginary spectrum is associated

with a gap, which, according to the criteria, is identified as a line gap. A detailed analysis of all these spectrum can be found in Ref.²⁷.

Once we have the energy spectrum as a function of Φ , we are ready to analyze the behavior of the persistent current. Since persistent current is essentially the slope of the ground state energy, let us first examine how the ground state energy behaves with the magnetic flux, considering both its real and imaginary parts. To compute the ground state energy E_G , we consider a relatively bigger ring size with number of unit cells $N = 20$ and fix the number of electrons $N_e = 20$, which is the half-filled case.

In the topological phase ($t_1 < t_2$), the real and imaginary parts of the ground state energy are depicted in Figs. 3(a) and (b), respectively. The real part of E_G shows sinusoidal behavior with Φ . The difference between the maximum and minimum magnitudes of $\text{Re}[E_G]$ is about 10^{-3} and this amount is spread over a full cycle of oscillation, that is 2π . Therefore, it is clear that the slope of the ground state energy would be very less, which consequently will reflect on the behavior of the current as we shall see. The imaginary part of the ground state energy, however, exhibits a periodic, parabola-like pattern with Φ , which is typically encountered in simple 1D metallic rings for the half-filled case. The imaginary part of E_G is discontinuous at $\Phi = 0$ and $\pm 2\pi$. The same periodicity is also observed in both the real and imaginary parts of the ground state energy, similar to the energy spectrum (Fig. 2).

At the transition point ($t_1 = t_2$), both the real and imaginary parts of E_G are identical as a function of Φ , as shown in Figs. 3(c) and (d), respectively. Here, the energy is also periodic with Φ , displaying a parabola-like pattern. This identical behavior is evident in view of the energy spectrum at the transition point (Figs. 2(c) and (d)). The E_G - Φ curves are found to be discontinuous at $\Phi = 0$ and $\pm 2\pi$.

In the trivial phase ($t_1 > t_2$), the behavior of the ground state energy is completely opposite to that in the topological phase. Here, the real part of E_G exhibits a parabola-like pattern (Fig. 3(e)), while the imaginary part of E_G shows sinusoidal behavior (Fig. 3(f)). Similar to the real part in the topological phase, for the imaginary part in the trivial phase, the difference between the maximum and minimum magnitudes of $\text{Re}[E_G]$ is about 5×10^{-3} , which is spread over a period of 2π . Consequently, the slope of the energy curve is less than that for the real part. The real part of E_G is also discontinuous at $\Phi = 0$ and $\pm 2\pi$.

The behavior of persistent current as a function of Φ is illustrated in Fig. 4 which we compute by taking the slope of the graphs in Fig. 3. All other system parameters are same as in Fig. 3.

The topological phase reveals an interesting feature regarding the real part of the persistent current, which is finite. This particular point has not been explored in previous works. In Ref.²⁷, it was stated that the persis-

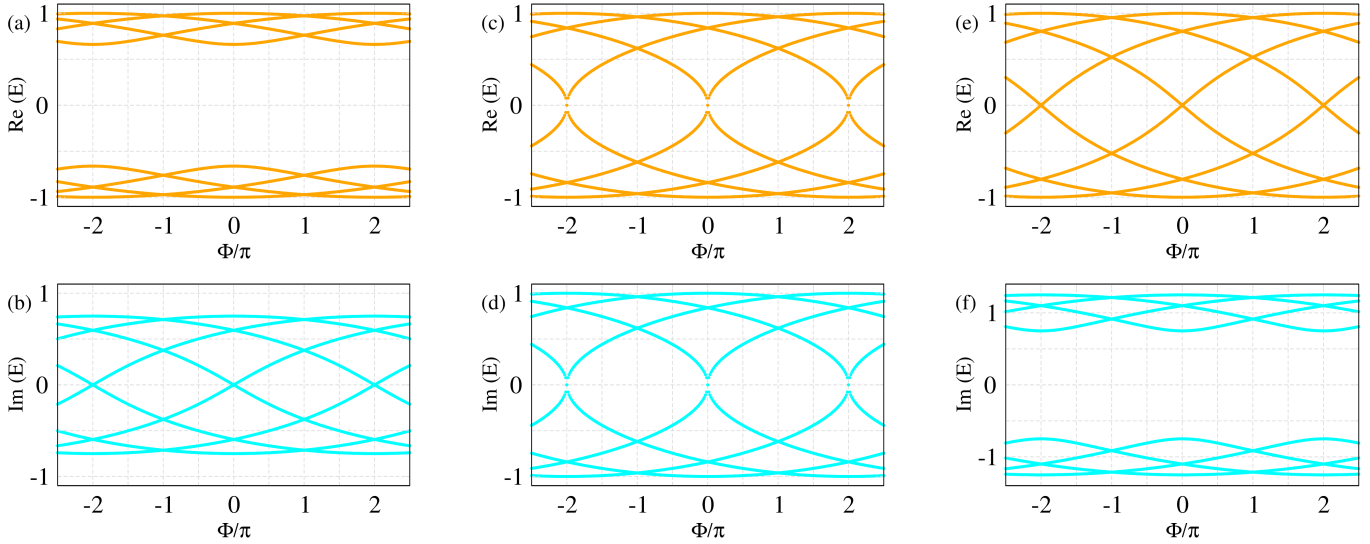


FIG. 2. (Color online.) Real and imaginary energy eigenspectra as a function of Φ , where the first, second and, third columns are for $t_1 = 0.75, 1,$ and $1.25,$ respectively. Here, the number of unit cells $N = 8$ and the intercell hopping strength $t_2 = 1.$

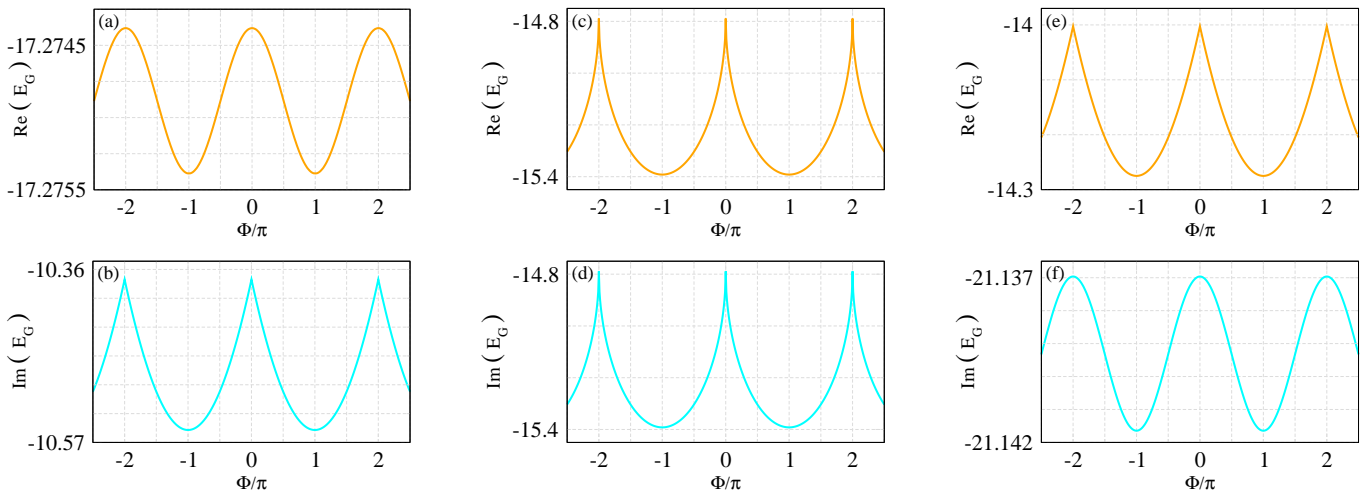


FIG. 3. (Color online.) Ground state energy E_G variation with Φ , where the first, second, and third columns are for $t_1 = 0.75, 1,$ and $1.25,$ respectively. Here, the number of unit cells $N = 20$ and the intercell hopping strength $t_2 = 1.$ Number of electrons is $N_e = 20.$

tent current is identically zero in the topological phase. However, as is clearly seen from Fig. 4(a), this is not the case. The magnitude is small ($\sim 0.03 \mu\text{A}$), as predicted from the ground state behavior, but it is finite for the considered ring size in the half-filled case. On the other hand, the imaginary current is quite large ($\sim 5 \mu\text{A}$) compared to its real counterpart and exhibits a saw-tooth pattern similar to that in Hermitian 1D rings⁵. Like the ground state energy, $\text{Im}[I]$ is also discontinuous at $\Phi = 0$ and $\pm 2\pi$. These are the points where $\text{Im}[E_G]$ changes the sign of the slope discontinuously. The periodicity in both cases is 2π .

At the transition point, the behavior of the real and imaginary parts of the persistent current is identical as a function of Φ , as shown in Figs. 4(c) and (d), respec-

tively. This is expected since the energy spectra and the ground state energies are identical for both the real and imaginary parts at the transition point. The persistent current can be obtained from the expression of the n -th energy level and is given by²⁷

$$I_n = \frac{-iI_0 t_1 \cos \phi_n}{\sqrt{t_2^2 - t_1^2 + 2it_1 t_2 \sin \phi_n}}.$$

Where $I_0 = 2\pi c t_2 / N \Phi_0$ and $\phi_n = \frac{2\pi}{N} \left(n + \frac{\Phi}{\Phi_0} \right)$. At $\Phi = 0$ and $\pm 2\pi$, the denominator becomes zero, as certain currents carried by their respective energy levels are undefined. For instance, the denominator becomes zero for $\phi_n = 0$, which happens for the level $n = 0$, and consequently, corresponding current becomes undefined. This

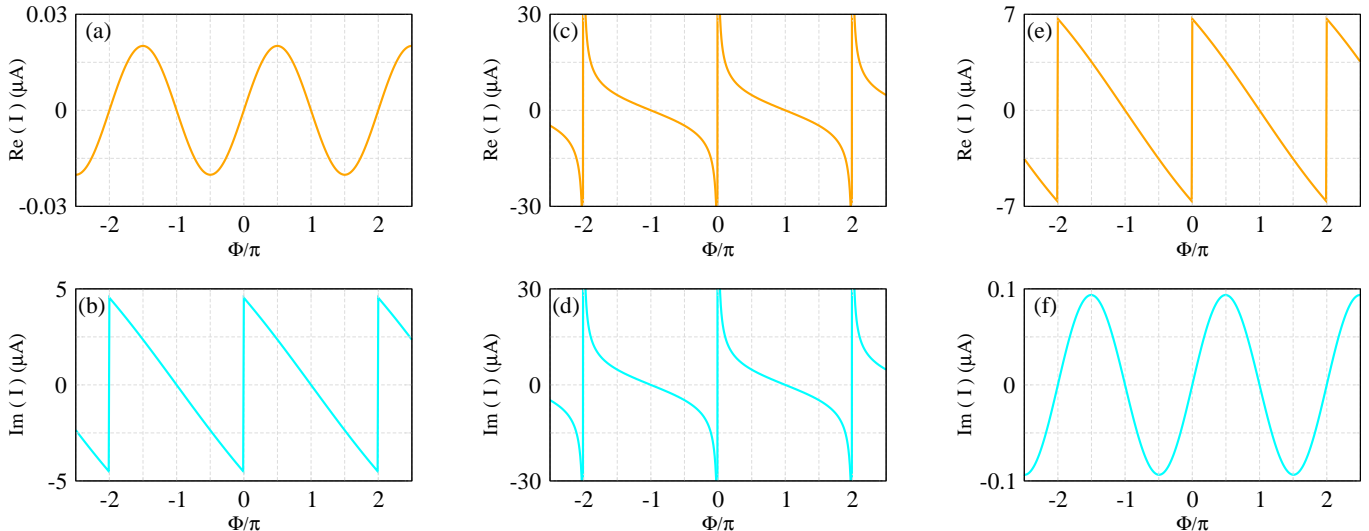


FIG. 4. (Color online.) Persistent current I versus magnetic flux Φ . The first, second, and third columns are for $t_1 = 0.75, 1,$ and 1.25 , respectively. All the other parameters are same as described in Fig. 3

is reflected in the I - Φ graphs, where both parts diverge at these points. Such divergences are quite sensitive to the number of electrons considered in the system.

The I - Φ characteristics in the trivial phase are completely opposite to those in the topological phase, as shown in Figs. 4(e) and (f). The real (imaginary) current exhibits a similar behavior to the imaginary (real) current in the topological phase. Another important unexplored point to note here is that the imaginary current is not identically zero but finite in the trivial phase (Fig. 4(f)).

In all the I - Φ plots, both the real and imaginary current are zero at $\Phi = 0, \pm\pi, \pm2\pi$. This is due to the fact that at $\Phi = 0, \pm2\pi$, the ground state energy is maximum, while at $\Phi = \pm\pi$, it is minimum. Since the current is proportional to the slope of the ground state energy, we get zero current at those Φ -values. These are also the points where all the currents change their sign from positive to negative or vice versa.

Overall, we find two important points from the above discussion. The real persistent current in the topological phase and the imaginary current in the trivial phase are not identically zero but finite for the considered system size and number of electrons. Now, let us see to what extent the persistent current remains non-zero as we increase the system size, knowing that with an increasing ring size, the current will eventually go to zero.

The behavior of persistent current with ring size is depicted in Fig. 5. In Fig. 5(a), we plot the maximum real current and in Fig. 5(b) the maximum imaginary current as a function of $2N$, the number sites in the system. The maximum current is obtained over a complete period, that is by varying the magnetic flux Φ from 0 to 2π . Here also we consider the half-filled case. The number of sites is chosen to be a multiple of 4 in order to have an even number of electrons for the half-filled case starting from $2N = 8$ to 120. For the transition point case, since both

the real and imaginary currents tend to diverge at $\Phi = 0$ and $\pm2\pi$, these points are excluded from the Φ -range, within which the maximum currents are picked up. Both the real and imaginary parts of the persistent current exhibit the usual decrease in magnitude as we increase the ring size. However, it is important to note that the

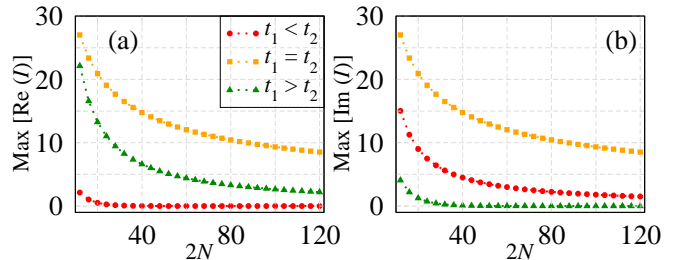


FIG. 5. (Color online.) Maximum persistent current versus number of sites $2N$ in the ring. (a) Real and (b) imaginary parts of the maximum current. Red, orange, and green curves represent the results corresponding to the topological phase, transition point, and trivial phase, respectively. The hopping parameters are the same as in the previous plots for the different phases. The current is computed for the half-filled case.

real part in the topological phase becomes zero beyond $2N \approx 20$ (Fig. 5(a)), while the imaginary part in the trivial phase becomes zero beyond $2N \approx 24$ (Fig. 5(b)). On the other hand, the real part in the trivial phase and the imaginary part in the topological phase decay slowly with the ring size. Even for a large system size, they attain a finite current. For instance the maximum current is about a few μA for $2N = 120$.

The filling factor, defined as the ratio between the current-carrying electronic states and the total number of electronic states, represents the number of electrons present in the system. It plays a crucial role in deter-

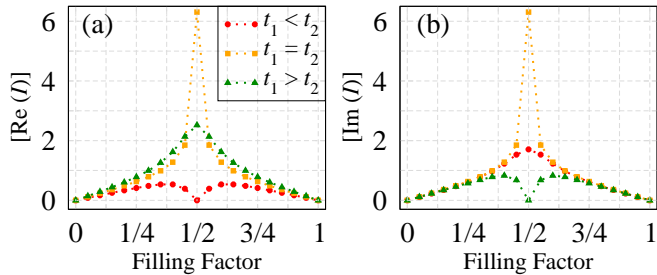


FIG. 6. (Color online.) Real and imaginary persistent current as a function of filling factor. (a) Real and (b) imaginary parts of the maximum current. The color schemes and the hopping parameters for different phases are the same as in Fig. 5. The system size is considered as $N = 40$. The flux is fixed at $\Phi = \pi/4$.

mining the behavior of persistent currents. To analyze this, we compute the currents as a function of the filling factor, as illustrated in Fig. 6(a) for the real part and for the imaginary part in Fig. 6(b). The color conventions are the same as in Fig. 5. The current profiles for all cases are symmetric about the half-filled case. This symmetry arises because the energy levels are symmetrically distributed around zero energy, as seen in Fig. 2. For the given system size ($2N = 80$), it is observed in the topological phase that the real current is zero (Fig. 5(a)), while the imaginary current is zero in the trivial phase (Fig. 5(b)). These observations were made for the half-filled case, which is also evident from Figs. 6(a) and 6(b). Interestingly, this is not the case for other filling factors. For example, in the window between the quarter-filled and half-filled cases in Fig. 6(a), the real current is not zero but has appreciable magnitudes (red curve). Similarly, for the imaginary part in the trivial phase (Fig. 6(b)), the green curve shows significant values. This clearly indicates that the current is highly sensitive to the filling factor. Moreover, the real (imaginary) current in the topological (trivial) phase attains its maximum value and gradually falls off on either side of the half-filled case. The same feature is also observed at the critical point $t_1 = t_2$ as shown by the orange curves.

B. Presence of disorder

1. AAH model

With a clear understanding of the persistent current in a non-Hermitian ring and a few unexplored features, we now turn our attention to the interplay between non-Hermiticity and disorder effects. To begin, we consider the AAH model and examine the behavior of the energy spectrum, as depicted in Fig. 7. For this study, we fix the number of unit cells to $N = 10$ and the disorder strength at $W = 0.5$.

In the topological phase, the real energy spectrum is significantly altered in the presence of AAH disorder, as

depicted in Fig. 7(a). Notably, the gap around zero energy remains intact despite the disorder. The inset of Fig. 7(a), showing the lower half of the real spectrum, reveals the presence of loop-like structures around $\Phi = 2n\pi$ ($n = 0, 1, 2, \dots$). The imaginary energy spectrum also experiences significant changes, as shown in Fig. 7(b), with the continuous evolution of imaginary eigenvalues completely disrupted by AAH disorder. An interesting observation is that these loop-like structures in the real spectrum persist within specific Φ -windows, and within these same Φ -windows, a few zero imaginary energies emerge. In both the real and imaginary spectra, the Φ periodicity remains 2π .

At the critical point, the previously observed identical behavior of the real and imaginary components of the energy spectrum (disorder-free case) is disrupted due to the presence of AAH disorder, as depicted in Figs. 7(c) and (d), respectively. Despite this, both spectra retain some of their characteristic features as a function of Φ , similar to their behavior in the topological phase. The real energy spectrum shows a noticeable reduction in the gap, while the imaginary energy spectrum becomes completely gapless. Additionally, loop-like structures persist in the real energy spectrum around the specific Φ values identified earlier. Around these Φ values, the imaginary energy spectrum also exhibits similar behavior to that observed in the topological phase.

In the trivial phase, the real and imaginary energy spectra exhibit similar characteristics as in the absence of AAH disorder, as shown in Figs. 7(e) and (f), respectively. The real energies evolve almost continuously, while the imaginary energy spectrum is characterized by a gap. Interestingly, the imaginary spectrum now displays loop-like structures at the same Φ -values previously noted for the real spectra in the topological phase. Overall, the presence of disorder breaks the symmetry of the real spectra around zero energy, while the imaginary components remain consistently symmetric.

To compute the ground state energy E_G in the presence of AAH disorder, we consider a relatively larger ring size with the number of unit cells set to $N = 20$ and fix the number of electrons at $N_e = 10$, corresponding to the quarter-filled case. The behavior of E_G as a function of Φ is shown in Fig. 8 for different values of t_1 under various disorder strengths. Specifically, we consider $W = 0, 0.25$, and 0.5 for illustration purposes, with their corresponding results represented in black, red, and cyan colors, respectively. The real part of E_G decreases at a particular disorder strength as we move from the topological phase (Fig. 8(a)) to the critical point (Fig. 8(c)) and further to the trivial phase (Fig. 8(e)). In contrast, the imaginary part of E_G increases as we progress from the topological phase (Fig. 8(b)) to the critical point (Fig. 8(d)) and finally to the trivial phase (Fig. 8(f)). This is physically understandable. As the intradimer hopping integral t_1 increases, the non-Hermiticity of the system becomes more pronounced, resulting in larger imaginary eigenenergies. The real part of E_G in the topological phase

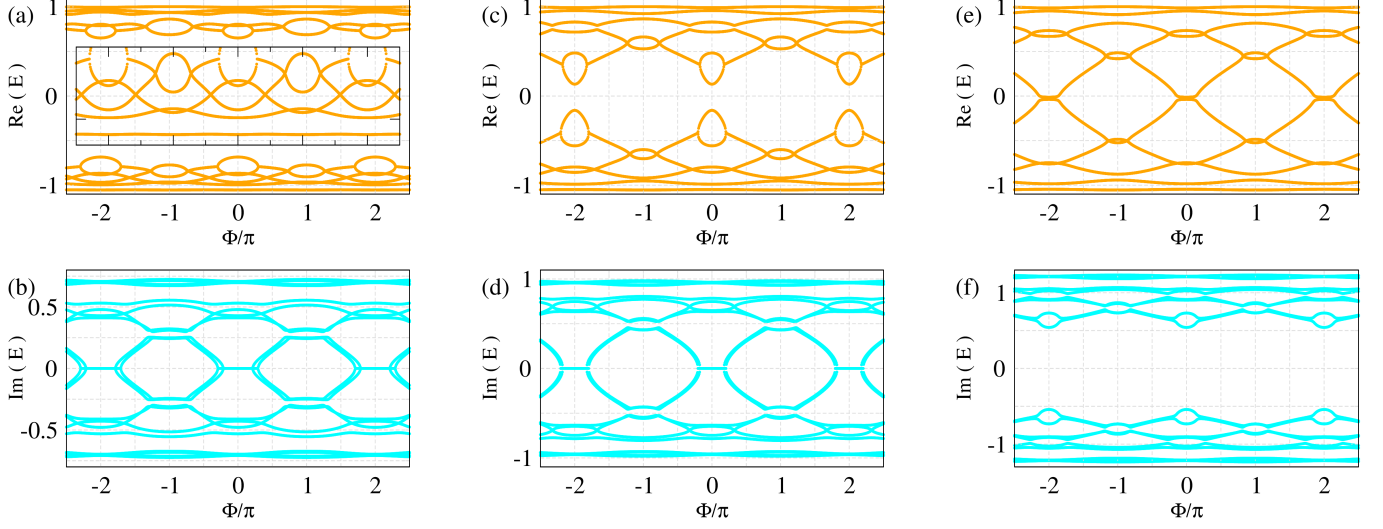


FIG. 7. (Color online.) Real and imaginary energy spectrum as a function of Φ in the presence of AAH disorder. (a) Real and (b) imaginary energies for $t_1 = 0.75$. (c) Real and (d) imaginary energies for $t_1 = 1$. (e) Real and (f) imaginary energies for $t_1 = 1.25$. Number of unit cells $N = 10$ and intercell hopping strength $t_2 = 1$. The AAH disorder strength is fixed at $W = 0.5$. An inset is shown in (a), where the lower half of the spectrum is zoomed in for clarity.

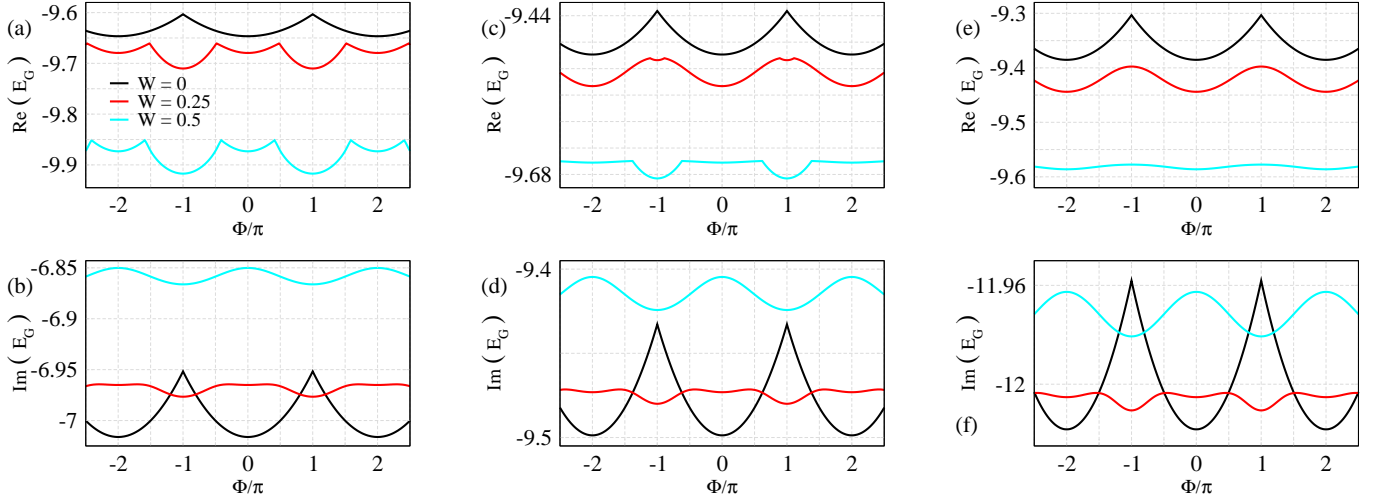


FIG. 8. (Color online.) Ground state energy E_G as a function of Φ in the presence of AAH disorder. (a) Real and (b) imaginary E_G for $t_1 = 0.75$. (c) Real and (d) imaginary E_G for $t_1 = 1$. (e) Real and (f) imaginary E_G for $t_1 = 1.25$. Number of unit cells $N = 20$ and intercell hopping strength $t_2 = 1$. The AAH disorder strength $W = 0, 0.25$, and 0.5 and the corresponding results are denoted with black, red, and cyan colors, respectively. Number of electrons is fixed at $N_e = 10$, which is the quarter-filled case.

exhibits a distinct feature in the presence of disorder. Within the Φ -window between -1 and 1 , the slope of the real ground state energy changes sign only once under clean conditions, but with disorder, the sign change occurs twice. At the critical point, this behavior is somewhat smoothed out in the presence of disorder, and in the trivial phase, the feature disappears entirely, becoming sinusoidal as a function of Φ . Apart from differences in magnitude, the imaginary part of E_G behaves in a similar manner across the three different regions when plotted as a function of Φ (Figs. 8(b), (d), and (f)), given a fixed dis-

order strength. The similarity in behavior implies that, although the AAH disorder strength introduces complexity, the primary features influencing the imaginary part of E_G are largely governed by the non-Hermiticity of the system across all regions.

The behavior of the persistent current as a function of Φ in the presence of AAH disorder is depicted in Fig. 9. All the system parameters, disorder strengths, electron filling factor, and color conventions are the same as those described in Fig. 8 and are also mentioned in the caption of Fig. 9. The real persistent current in the topolog-

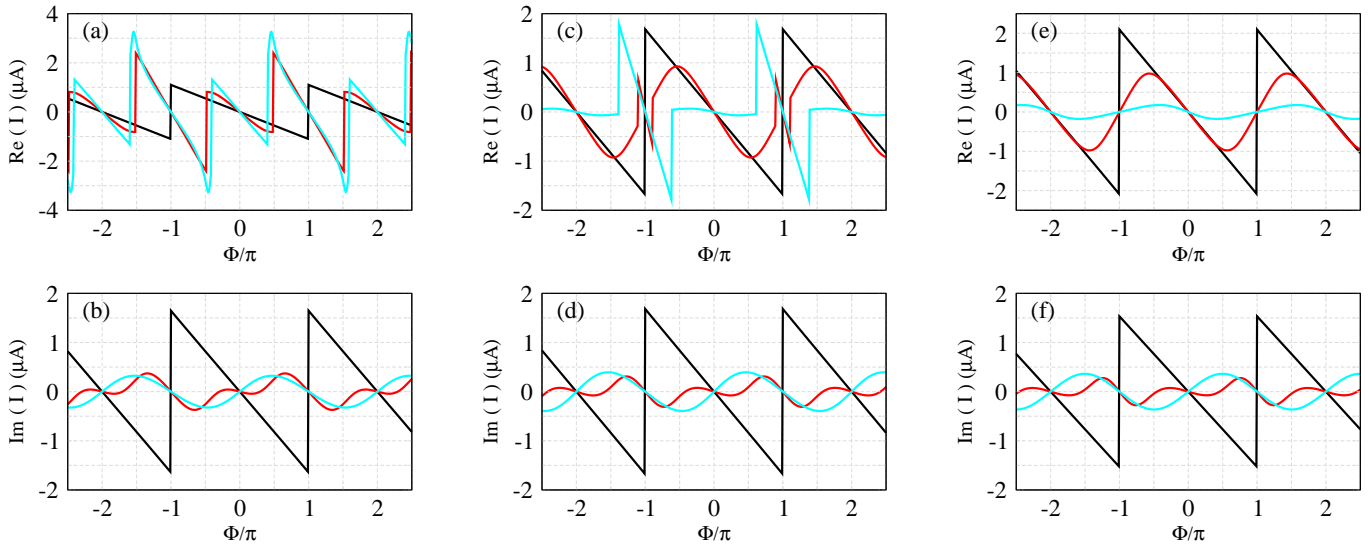


FIG. 9. (Color online.) Persistent current I as a function of Φ in the presence of AAH disorder. (a) Real and (b) imaginary I for $t_1 = 0.75$. (c) Real and (d) imaginary I for $t_1 = 1$. (e) Real and (f) imaginary I for $t_1 = 1.25$. Number of unit cells $N = 20$ and intercell hopping strength $t_2 = 1$. The AAH disorder strength $W = 0, 0.25$, and 0.5 and the corresponding results are denoted with black, red, and cyan colors, respectively. Number of electrons is fixed at $N_e = 10$, which is the quarter-filled case.

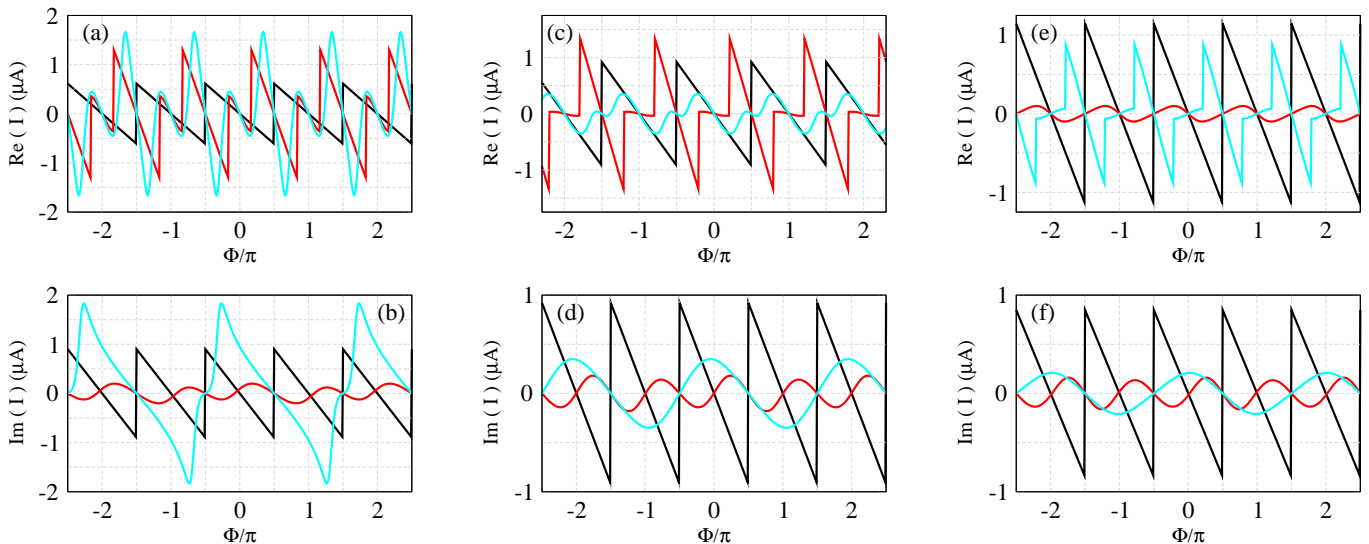


FIG. 10. (Color online.) Persistent current I as a function of Φ in the presence of Fibonacci disorder. (a) Real and (b) imaginary I for $t_1 = 0.75$. (c) Real and (d) imaginary I for $t_1 = 1$. (e) Real and (f) imaginary I for $t_1 = 1.25$. The intercell hopping strength $t_2 = 1$. The AAH disorder strength $W = 0, 0.25$, and 0.5 and the corresponding results are denoted with black, red, and cyan colors, respectively. Number of unit cells is $N = 17$ and the number of electrons is fixed at $N_e = 8$, which is close to the quarter-filled case.

ical phase exhibits two distinct anomalous features, as shown in Fig.9(a). First, in the presence of AAH disorder with $W = 0.25$, the real persistent current (red curve) is higher than in the disorder-free case (black curve), and with $W = 0.5$, the current increases further compared to $W = 0.25$. This indicates that increasing disorder strength enhances the current amplitude, which is unexpected. Second, while the current typically changes sign only once within the usual flux period of 2π , the

presence of AAH disorder causes the sign change to occur twice. This behavior is consistent with the ground state energy plot discussed in Fig.8. Both of these features are highly atypical for disordered ring systems. At the critical point, the current behavior changes from the previous scenario. For $W = 0.25$, the current is reduced compared to the disorder-free case, as shown in Fig. 9(c). However, as disorder strength increases to $W = 0.5$, the current not only recovers but also exceeds the maximum

value observed without disorder, demonstrating that current amplification remains significant even at the critical point. Although the sign change in the current is less pronounced than before, it is still present, indicating that disorder continues to influence the phase of the current, albeit more subtly. In contrast, the current amplification effect is entirely absent in the trivial phase, as depicted in Fig. 9(e). Here, the real current decreases systematically with increasing disorder strength. In the absence of disorder, the current exhibits a sawtooth-like behavior, but with disorder, it becomes sinusoidal as a function of Φ , without any additional sign changes in the current. The most important observation from the above analysis is that AAH disorder leads to a favorable transport, as discussed in recent works^{35,36}.

The imaginary persistent current, in the absence of disorder, exhibits a sawtooth-like behavior across all three regions: the topological phase (Fig. 9(b)), the critical point (Fig. 9(d)), and the trivial phase (Fig. 9(f)). In terms of magnitude, it remains largely unchanged. In the presence of AAH disorder, while the magnitude of the imaginary current consistently decreases with increasing disorder strength, the overall behavior remains similar in all three regions, showing no significant qualitative changes.

2. Fibonacci model

Next, we consider correlated disorder following the Fibonacci sequence and examine the behavior of both the real and imaginary components of the persistent current as a function of magnetic flux, Φ , as depicted in Fig. 10. In this case, the number of unit cells is fixed at $N = 17$, corresponding to 34 total sites—a value from the Fibonacci sequence. The number of electrons is set to $N_e = 8$, which is close to the quarter-filling case. The remaining parameters, including disorder strengths and color conventions, are the same as in Fig. 9. The behavior of the real persistent current in the topological phase follows a similar pattern to that observed under AAH disorder, as shown in Fig. 10(a). Specifically, the current increases as the strength of Fibonacci (FB) disorder increases. A key distinction, however, is that in the FB case, the current changes sign four times, whereas for AAH disorder, the sign reversal occurs only twice. At the critical point, the real current at $W = 0.25$ (red curve) is greater than in the absence of disorder (black curve). However, as the disorder strength continues to increase, the current diminishes, as depicted in Fig. 10(c). At $W = 0.5$ (cyan curve), the current reaches its lowest value, which is lower than both the disorder-free case and the $W = 0.25$ scenario. Interestingly, the number of sign changes at $W = 0.5$ remains the same as in the topological phase. In the trivial phase, the current at $W = 0.25$ is lower than in the disorder-free case, but it reaches a maximum at $W = 0.5$, as shown in Fig. 10(e). However, in contrast to the topological phase, the current

only changes sign twice in the trivial phase.

The amplification of the current is also evident in the behavior of the imaginary persistent current in the topological region, as shown in Fig. 10(b). In this case, the current at $W = 0.25$ is lower than in the disorder-free case, but interestingly, it reaches its maximum at $W = 0.5$. At the critical point, as seen in Fig. 10(d), the imaginary current is highest when no disorder is present, but the current at $W = 0.5$ still exceeds that at $W = 0.25$. In the trivial phase, depicted in Fig. 10(f), the imaginary current follows the typical trend observed with increasing disorder strength, steadily decreasing as the disorder strength grows.

3. Random disorder

The effect of random disorder on persistent currents is also explored in this study, with the behavior of the current as a function of Φ shown in Fig. 11. The system, consisting of $N = 20$ unit cells (as in the AAH model), is set to a quarter-filled case, that is $N_e = 10$. Currents are determined by averaging over 100 random disorder configurations. In contrast to correlated disorder, both the real and imaginary components of the persistent current exhibit a characteristic decreasing trend with increasing disorder strength across all scenarios.

It is essential to note that, although the averaged currents consistently show this decreasing trend, they reflect an ensemble average over all random configurations. A closer examination of individual random configurations reveals that a subset does exhibit current amplification. Nonetheless, as the majority of configurations align with the conventional decreasing trend, and given that persistent currents from different configurations also vary in sign at a fixed Φ , the overall averaged effect remains a net decrease in the persistent current under random disorder. The behavior of persistent currents for a representative configuration is additionally illustrated in Fig. S1 of the supporting material.

To gain a comprehensive understanding of the impact of disorder on the persistent current, we vary the disorder strength over a complete flux period, ranging from $-\pi$ to π , and focus on the maximum amplitude of the current, denoted as $\text{Max}[I]$. The behavior of $\text{Max}[I]$ as a function of AAH disorder strength is shown in Figs. 12(a) and (b) for the real and imaginary components, respectively.

In Fig. 12(a), the real persistent current exhibits intriguing behavior in response to disorder. In the topological phase, the current increases with disorder strength, showing fluctuations, reaches a maximum at $W = 1$, and then drops sharply, becoming nearly zero beyond this point. At the critical point, the current initially decreases with disorder strength up to $W \sim 0.25$, after which it begins to increase with fluctuations and reaches its highest value around $W \approx 1.25$. However, beyond this threshold, the current drops abruptly to zero. A similar pattern is observed in the trivial phase, where the maximum

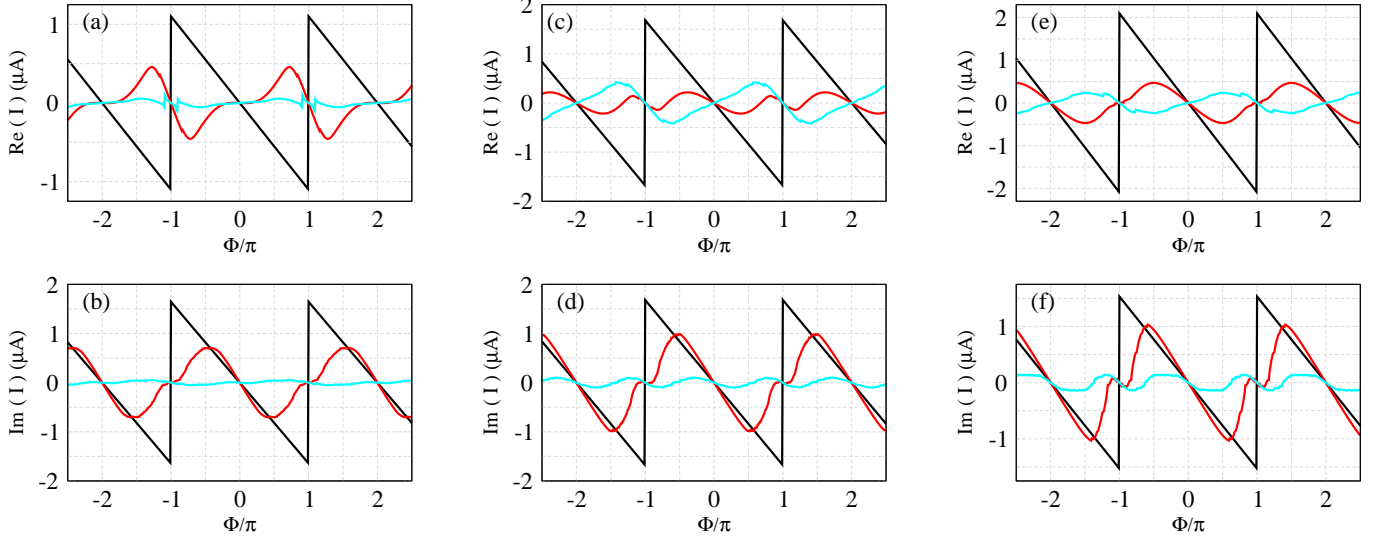


FIG. 11. (Color online.) Persistent current I as a function of Φ in the presence of random disorder. (a) Real and (b) imaginary I for $t_1 = 0.75$. (c) Real and (d) imaginary I for $t_1 = 1$. (e) Real and (f) imaginary I for $t_1 = 1.25$. The intercell hopping strength $t_2 = 1$. The AAH disorder strength $W = 0, 0.25$, and 0.5 and the corresponding results are denoted with black, red, and cyan colors, respectively. Number of unit cells is $N = 20$ and the number of electrons is fixed at $N_e = 10$, which is the quarter-filled case. All the currents are averaged over 100 configuration.

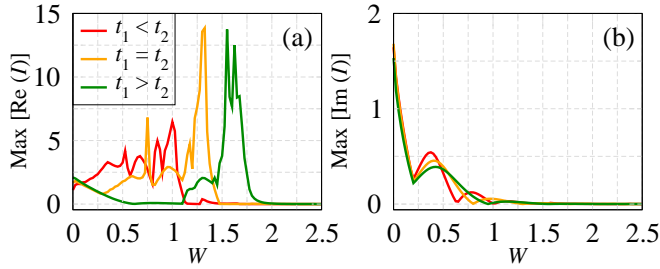


FIG. 12. (Color online.) $\text{Max}[I]$ as a function of AAH disorder strength. (a) Real and (b) imaginary currents. The number of unit cells is $N = 20$ and number of electrons is fixed at $N_e = 10$. Definition of $\text{Max}[I]$ is described in the texts. Red, orange, and green colors represent the result corresponding to the topological phase, critical point, and trivial phase, respectively.

current occurs at a higher disorder strength compared to the other two cases. This trend indicates that the critical disorder strength, beyond which the real current becomes vanishingly small, increases with the intradimer hopping integral t_1 .

This behavior is physically intuitive. As t_1 increases, the kinetic energy of the electrons also increases, requiring a higher critical disorder strength to fully localize the system. Thus, a stronger disorder is needed to suppress the current when the electrons are more mobile.

On the other hand, the imaginary persistent current follows a different pattern, as shown in Fig. 12(b). It decreases steadily with increasing disorder strength up to $W \approx 0.25$, where it shows a small hump across all the phases. Beyond this point, the current decreases again

as W continues to increase. Overall, current amplification is more pronounced in the real part compared to the imaginary part in the presence of AAH disorder.

The behavior of persistent current with FB disorder strength is presented in Fig. 13, where the number of unit cells is set at $N = 17$ and the number of electrons is fixed at $N_e = 8$. The definition of $\text{Max}[I]$ is the same as in Fig. 12, and the color conventions re-

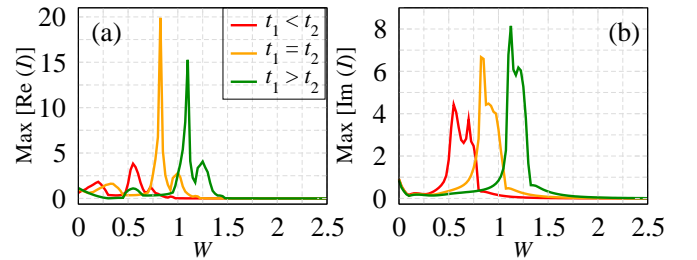


FIG. 13. (Color online.) $\text{Max}[I]$ as a function of Fibonacci disorder strength. (a) Real and (b) imaginary currents. The number of unit cells is $N = 17$ and number of electrons is fixed at $N_e = 8$. Definition of $\text{Max}[I]$ is described as in Fig. 12. Red, orange, and green colors represent the result corresponding to the topological phase, critical point, and trivial phase, respectively.

main consistent. For the real persistent current, a similar trend to that observed in the AAH case is seen, as shown in Fig. 13(a). The critical disorder strength, beyond which the real current becomes vanishingly small, increases with the intradimer hopping integral, just as in the AAH case. This indicates that higher disorder strength is required to fully localize the system as elec-

tron mobility increases with higher intradimer hopping. The imaginary persistent current exhibits a distinct and interesting pattern across the three phases. Initially, in all phases, the imaginary current decreases with increasing disorder strength, W . However, as W continues to rise, the current begins to increase, reaches a maximum, and then sharply drops to zero due to the onset of localization. Overall, in the presence of FB disorder, both the real and imaginary currents exhibit current amplification.

A note on critical point: So far, we have defined the critical point as the condition $t_1 = t_2$. However, in the presence of disorder, as shown in Fig. 7, the identical behavior between the real and imaginary parts of the energy spectrum is disrupted. Nonetheless, both the real and imaginary components retain their line-gap properties in the topological and trivial phases, respectively. Interestingly, at the critical point, the real line-gap structure is preserved (Fig. 7(c)). This raises an important question regarding the validity of the critical point under disorder: should the condition $t_1 = t_2$ still be considered a critical point in the presence of disorder? Alternatively, does the critical point shift to different values of the hopping integrals, or is it altogether destroyed, implying no such critical point remains under disorder? To resolve this issue, we study the behavior of real and imaginary energies as a function of the intradimer hopping integral t_1 as shown in Fig. 14.

We begin by discussing the behavior of real and imaginary energies as a function of t_1 for the disorder-free case, as illustrated in Figs. 14(a) and (b), respectively. In Fig. 14(a), the real energy spectrum reveals a gap in the range $t_1 = 0$ to 1, beyond which a zero-energy line emerges. This is further validated by the inset in Fig. 14(a), where it is evident that precisely at $t_1 = 1$, a zero-energy line forms. For the imaginary part, shown in Fig. 14(b), a zero-energy line persists up to $t_1 = 1$. Beyond this point, a gap appears.

Introducing disorder at $W = 0.25$, we observe that the real energy spectrum continues to display a gap up to $t_1 = 1$, followed by the emergence of a zero-energy line. However, as shown in the inset of Fig. 14(c), no zero-energy line exists beyond $t_1 = 1$ within the given range of intradimer hopping integrals. In the case of imaginary energies (Fig. 14(d)), and as highlighted in the inset, the gap opens not exactly at $t_1 = 1$ but at a slightly higher value.

For a larger disorder strength, $W = 2$, the real energy spectrum clearly lacks a zero-energy line, as shown in Fig. 14(e). The imaginary energy spectrum in Fig. 14(f) further reveals that the gap opens around $t_1 = 2$. Thus, the presence of disorder disrupts the real energy gap entirely, while the imaginary gap persists but shifts to higher values of t_1 as disorder increases. The greater the disorder, the higher the intradimer hopping integral required for the imaginary line gap to appear. It can be emphasized that the features of critical point disappear in the presence of disorder.

Bond-resolved analysis of persistent currents: It is also interesting to study the distribution of persistent current across the bonds. For that, we adopt the current operator method. The current operator is defined as³⁷

$$\hat{J} = \frac{e\dot{X}}{2Na}, \quad (7)$$

where e is the electronic charge, \dot{X} is the velocity operator, $2N$ is the number of sites, and a is the lattice spacing. The velocity operator is further defined as

$$\dot{X} = \frac{2\pi}{i\hbar}[X, H], \quad (8)$$

where X is the position operator and H is the system Hamiltonian as in Eq. 1. The position operator can be expressed in terms of the fermionic operators as

$$X = \sum_{n=1}^N na \left(c_{n,A}^\dagger c_{n,A} + c_{n,B}^\dagger c_{n,B} \right). \quad (9)$$

By taking the commutator between X and H , the current operator gets the following form

$$\begin{aligned} \hat{J} &= \frac{2\pi e|t_1|}{i(2N)\hbar} \sum_{n=1}^N \left(e^{i\phi} c_{n,A}^\dagger c_{n,B} + e^{-i\phi} c_{n,B}^\dagger c_{n,A} \right) \\ &+ \frac{2\pi e t_2}{i(2N)\hbar} \sum_{n=1}^{N-1} \left(c_{n,B}^\dagger c_{n+1,A} - c_{n+1,A}^\dagger c_{n,B} \right) \\ &+ \frac{2\pi e t_2}{i(2N)\hbar} \left(c_{N,B}^\dagger c_{1,A} - c_{1,A}^\dagger c_{N,B} \right). \end{aligned} \quad (10)$$

For an m -th eigenstate $|\psi_m\rangle$, the persistent current can be calculated as

$$I_m = \langle \psi_m | \hat{J} | \psi_m \rangle, \quad (11)$$

where $|\psi_m\rangle = \sum_p (u_{p,A}^m |p, A\rangle + u_{p,B}^m |p, B\rangle)$. Here $|p, A\rangle$ and $|p, B\rangle$ are the Wannier states and $u_{p,A}^m$ and $u_{p,B}^m$ are the corresponding coefficients. The current for the m -th eigenstate takes the form

$$\begin{aligned} I_m &= \frac{2\pi e|t_1|}{i(2N)\hbar} \sum_{p=1}^N \left[e^{i\phi} (u_{p,A}^m)^* u_{p,B}^m + e^{-i\phi} (u_{p,B}^m)^* u_{p,A}^m \right] \\ &+ \frac{2\pi e t_2}{i(2N)\hbar} \sum_{p=1}^{N-1} \left[(u_{p,B}^m)^* u_{p+1,A}^m - (u_{p+1,A}^m)^* u_{p,B}^m \right] \\ &+ \frac{2\pi e t_2}{i(2N)\hbar} \left[(u_{N,B}^m)^* u_{1,A}^m - (u_{1,A}^m)^* u_{N,B}^m \right]. \end{aligned} \quad (12)$$

The net persistent current for the occupied electronic states will be

$$I = \sum_m I_m. \quad (13)$$

The real and imaginary parts of Eq. 13 can be extracted to compute the real and imaginary components

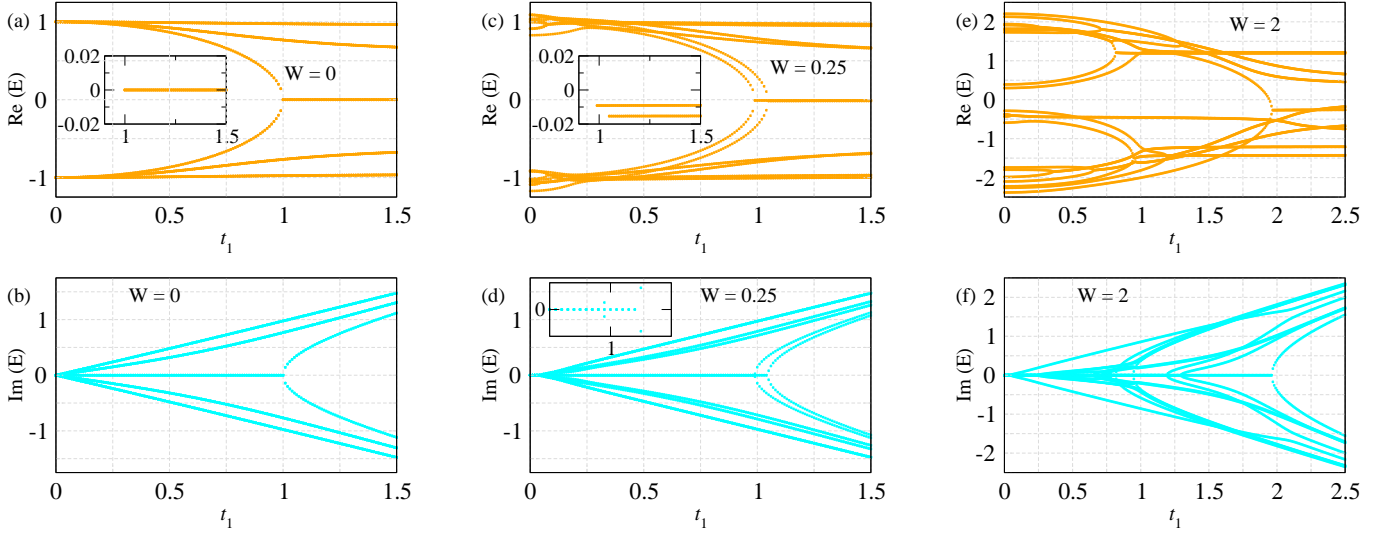


FIG. 14. (Color online.) Energy spectrum as a function of intradimer hopping integral t_1 in the presence of AAH disorder. (a) Real and (b) imaginary for $W = 0$. (c) Real and (d) imaginary E for $W = 0.25$. (e) Real and (f) imaginary E for $W = 2$. The interdimer hopping integral is fixed at $t_2 = 1$ and magnetic flux at $\Phi = 0$. Number of unit cells $N = 10$.

of the persistent current. Notably, both the derivative method (outlined in Sec. II) and the operator method produce identical results. However, the latter method offers the advantage of calculating the current across different bonds directly from Eq.12. The current through any intradimer bond (from site p to q) for the occupied electronic states can be written as

$$I_{pq} = \frac{2\pi e|t_1|}{i(2N)\hbar} \sum_m \left[e^{i\phi} (u_{p,A}^m)^* u_{q,B}^m + e^{-i\phi} (u_{q,B}^m)^* u_{p,A}^m \right], \quad (14)$$

while, that through any inter-dimer bond for the occupied electronic states is

$$I_{pq} = \frac{2\pi e t_2}{i(2N)\hbar} \sum_m \left[(u_{p,B}^m)^* u_{q,A}^m - (u_{q,A}^m)^* u_{p,B}^m \right]. \quad (15)$$

A careful inspection of Eqs. 14 and 15 reveals a unique property of the bond-resolved persistent current. In Eq.15, the second term within the parentheses is the complex conjugate of the first term. Since the amplitudes $u_{p,A}^m$ and $e^{i\phi}$ are generally complex, the expression inside the parentheses becomes a real quantity. Consequently, with the factor i outside the parentheses, the current through the intra-dimer bond is always imaginary. Similarly, for the inter-dimer bond, the current is always a real quantity. This behavior persists both in the absence and presence of disorder and is illustrated in Fig. 15 within the topological phase. The bond currents are plotted as a function of Φ for the half-filled case, focusing on the intra-dimer bond between sites 1 and 2 (I_{12}) and the inter-dimer bond between sites 2 and 3 (I_{23}). The real parts are shown in Fig. 15(a), while the imaginary parts are depicted in Fig.15(b). All system parameters match those used in Fig. 4(a). The real and imaginary currents are represented by blue and red lines,

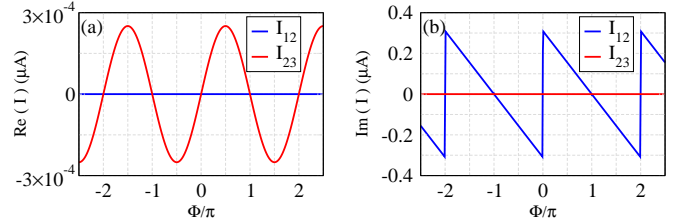


FIG. 15. (Color online.) Bond currents I_{12} and I_{23} as a function of ϕ . (a) Real and (b) imaginary currents in the topological phase with $t_1 = 0.75$ and $t_2 = 1$. The number of unit cells is $N = 20$ and number of electrons is fixed at $N_e = 20$. The red and blue colors denote the real and imaginary currents, respectively.

respectively. Consistent with the bond current expressions, the real part of the current is identically zero for the intradimer bond in Fig.15(a), while a finite imaginary current appears in Fig. 15(b). Conversely, the interdimer bond exhibits the opposite behavior. Furthermore, we observe that all intradimer bonds carry identical imaginary currents, while all inter-dimer bonds carry identical real currents. However, for the sake of brevity, this result is not explicitly shown in the present work. Thus, in such NH systems, real and imaginary bond currents appear alternately which is in complete contrast to the Hermitian ones.

IV. SUMMARY

This work investigates the interplay of topology, diagonal disorder, and non-Hermiticity in the behavior of persistent current within the Hatano-Nelson ring. Non-

Hermiticity is introduced through the anti-Hermitian intradimer hopping integral, which acts as a synthetic magnetic field. We consider disorder using two widely studied correlated disorder models, namely the AAH model and the FB model. For completeness, we also examine uncorrelated (random) disorder. Our analysis encompasses the energy spectrum, ground state energy, and the persistent current, including both real and imaginary components, under varying conditions in the absence and presence of disorder.

In the absence of disorder, we uncover that the behavior of persistent current strongly depends on the topology of the system and filling factor. In the topological (trivial) phase, the real (imaginary) persistent current is strictly zero, as indicated in recent work²⁷. However, this statement is only valid for larger ring systems in the half-filled case. The revised conclusion we draw is that in the topological (trivial) phase, the imaginary (real) persistent current is the dominant one, while the real (imaginary) current remains weak. As the system size increases, both the real and imaginary currents decrease toward zero. Even in larger ring systems, the topological (trivial) phase may host a real (imaginary) persistent current for specific filling factors, other than the half-filled case.

The effect of AAH disorder introduces complexity into the real and imaginary energy spectra while preserving the primary features observed in the absence of disorder. In the topological phase, a real line gap is present, while the trivial phase hosts an imaginary line gap. Notably,

the real and imaginary energy spectra lose their identical behavior characteristic of the disorder-free scenario.

In the topological phase, the real persistent current exhibits an intriguing amplification phenomenon as the disorder strength increases, particularly at the critical point. In contrast, the imaginary persistent current follows a conventional decreasing trend with increasing disorder.

On the other hand, FB disorder leads to current amplification in both the real and imaginary persistent currents. In the case of uncorrelated disorder, no atypical behavior is observed overall. Interestingly, some individual uncorrelated configurations do exhibit current amplification, which, however, disappears when averaged over multiple configurations, indicating that while individual realizations may show enhanced current, the average effect does not sustain this phenomenon.

The final observation from the analysis of bond-resolved currents is that the complex persistent current in the ring flows as alternating real and imaginary currents through the bonds. Specifically, the intra-dimer bonds exclusively host imaginary currents, while the inter-dimer bonds carry only real currents.

Overall, our findings illustrate the intricate interplay between disorder and persistent current in various topological phases, emphasizing the importance of disorder type and configuration in determining the behavior of these currents. The exploration of these effects not only enriches our understanding of non-Hermitian quantum systems but also suggests potential avenues for future research into disorder-induced phenomena.

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Supplemental Materials: Persistent current in a non-Hermitian Hatano-Nelson ring: Disorder-induced amplification

Figure S1 illustrates the behavior of the real and imaginary components of the persistent current as a function of Φ for a specific random configuration. Here, the current amplification is evident in both components across different phase values, showcasing deviations from the average trend observed in the ensemble analysis in the main text.

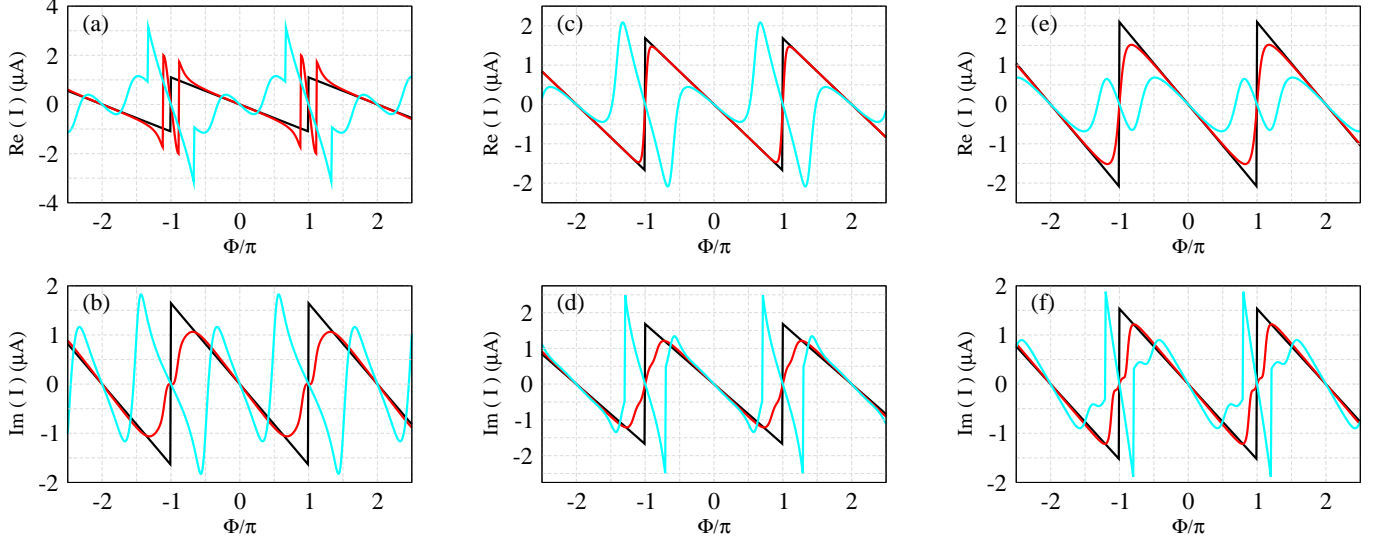


FIG. S1. (Color online.) Persistent current I as a function of Φ in the presence of random disorder for a single configuration. (a) Real and (b) imaginary I for $t_1 = 0.75$. (c) Real and (d) imaginary I for $t_1 = 1$. (e) Real and (f) imaginary I for $t_1 = 1.25$. The intercell hopping strength $t_2 = 1$. Disorder strengths $W = 0, 0.25, \text{ and } 0.5$ and the corresponding results are denoted with black, red, and cyan colors, respectively. Number of unit cells is $N = 20$ and the number of electrons is fixed at $N_e = 10$, which is the quarter-filled case.